





150V NPN LED DRIVING TRANSISTOR IN SOT89

Features

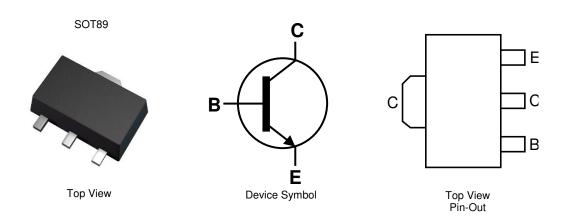
- BV_{CEO} > 150V
- I_C = 1A High Continuous Current
- $h_{FE} > 100$ for $I_C = 150mA$, $V_{CE} = 0.25V$
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.055 grams (Approximate)

Applications

LED TV Backlight



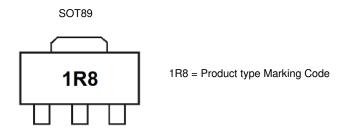
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN4004ZTA	AEC-Q101	1R8	7	12	1,000 units
ZXTN4004ZQTA	Automotive	1R8	7	12	1.000 units

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	200	V
Collector-Emitter Voltage	V_{CEO}	150	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	Ісм	3	Α
Base Current	I_{B}	500	mA

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1		
Power Dissipation	(Note 7)	P_{D}	1.5	W	
	(Note 8)		2.0		
	(Note 6)		125		
Thermal Resistance, Junction to Ambient Air	(Note 7)	$R_{\theta JA}$	83	°C/W	
	(Note 8)		60		
Thermal Resistance, Junction to Lead	$R_{ heta JL}$	13	°C/W		
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

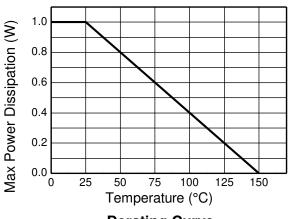
 8. Same as Note 6, except the device is mounted on 50mm x 50mm 1oz copper.

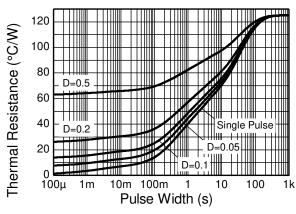
- Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.





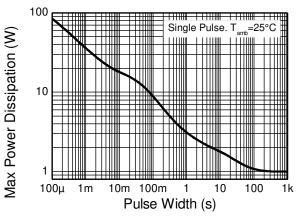
Thermal Characteristics and Derating Information



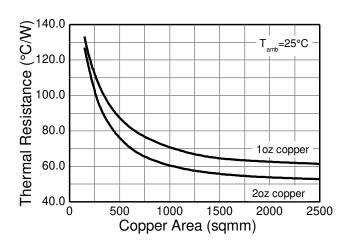


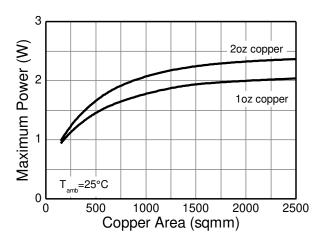
Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





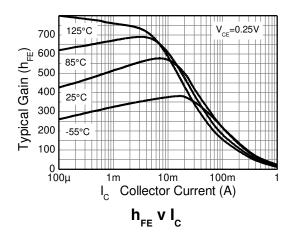


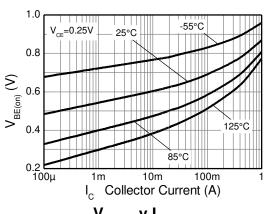
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

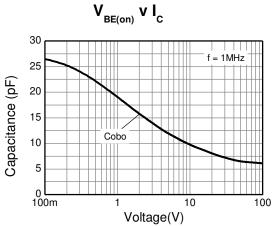
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	150	175	-	V	$I_C = 10mA$
Collector-Base Breakdown Voltage	BV _{CBO}	200	310	-	V	$I_C = 100\mu A$
Collector Cut-Off Current	I _{CBO}	-	<1	50	nA	V _{CB} = 150V
Collector Cut-Off Current	I _{CES}	-	<1	50	nA	V _{CE} = 150V
Emitter Cut-Off Current	I _{EBO}	-	<1	50	nA	$V_{EB} = 7V$
		200	-	-		$I_C = 30mA$, $V_{CE} = 5V$
Static Forward Current Transfer Ratio (Note 11)	h _{FE}	60	-	-	-	$I_C = 85 \text{mA}, V_{CE} = 0.20 \text{V}$
		100	-	-		$I_C = 150 \text{mA}, V_{CE} = 0.25 \text{V}$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	-	0.71	0.95	V	$I_C = 150 \text{mA}, V_{CE} = 0.25 \text{V}$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	-	-	0.25	V	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
Delay Time	t _(d)	-	512	-	ns	
Rise Time	t _(r)	-	426	-	ns	$V_{CC} = 120V, I_C = 150mA,$
Storage Time	t _(s)	-	3413	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 0.25 \text{V}$
Fall Time	t _(f)	-	321	-	ns	
Storage Time	t _(s)	-	65	-	ns	V _{CC} = 120V, I _C = 150mA,
Fall Time	t _(f)	-	294	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 4V$

Note: 11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)





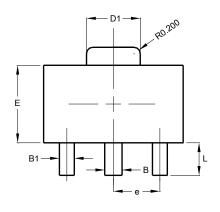


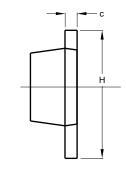
Capacitance v Voltage

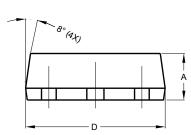


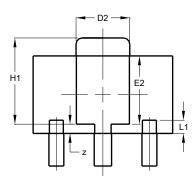
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.





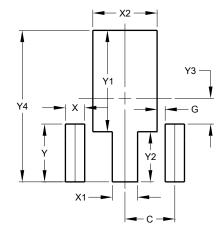




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
C	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimonolono	value			
Dimensions	(in mm)			
С	1.500			
G	0.244			
X	0.580			
X1	0.760			
X2	1.933			
Υ	1.730			
Y1	3.030			
Y2	1.500			
Y3	0.770			
Y4	4.530			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.





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